

6N138, 6N139 Low Input Current Photodarlington Coupler

Features

- Low current 0.5mA
- Superior CTR-2000%
- CTR guaranteed 0–70 ℃

Applications

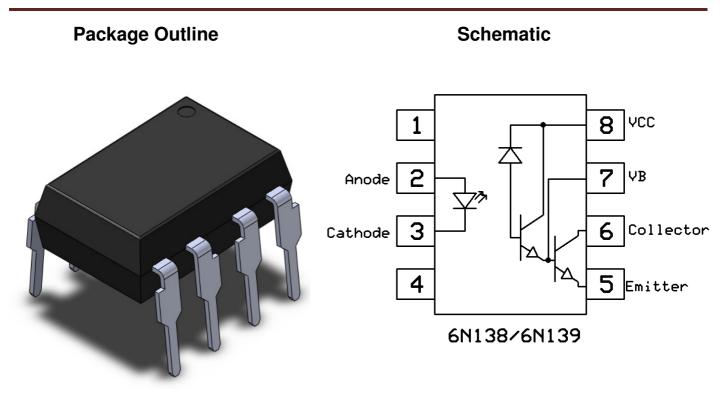
- Digital logic ground isolation
- Telephone ring detector
- EIA-RS-232C line receiver
- High common mode noise line receiver
- μ P bus isolation
- Current loop receiver

Description

The 6N138 & 6N139 optocouplers consist of an AlGaAs LED optically coupled to a high gain split darlington photodetector.

The combination of a very low input current of 0.5mA and a high current transfer ratio of 2000% makes this family particularly useful for input interface to MOS, CMOS, LSTTL and EIA RS232C, while output compatibility is ensured to CMOS as well as high fan-out TTL requirements.

The devices are packaged in an 8-pin DIP package and also available in gullwing (400mil) spacing and surface mount lead forming option.



Note: Different lead forming options available. See package

dimension.



Low Input Current Photodarlington Coupler

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes	
Viso	Isolation voltage	5000	VRMS		
Topr	Operating temperature		-55 ~ +100	°C	
Тѕтс	Storage temperature		-55 ~ +125	°C	
TSOL	Soldering temperature		260	°C	
Emitter					
lF	Forward current		25	mA	
IFP	Peak forward current (50% duty, 1ms P.W)		50	mA	
F(TRANS)	Peak transient current (≤1µs P.W,300pps)	1	А		
V_{R}	Reverse voltage	5	V		
PD	Power dissipation	40	mW		
Detector	-				·
PD	Power dissipation		100	mW	
VEBR	Emitter-Base reverse voltage		0.5	V	
lo	Output Current	60	mA		
		6N138	-0.5 to 7	V	
Vo	Output voltage 6N139	6N139	-0.5 to 18	V	
N/	Queeluustese	6N138	-0.5 to 7	V	
Vcc	Supply voltage	6N139	-0.5 to 18	V	



Electrical Characteristics $T_A = 0 - 70 \ C$, $V_{cc} = 4.5V$ (unless otherwise specified).

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I⊧ = 16mA	-	1.45	1.6	V	
IR	Reverse Current	$V_{R} = 5V$	-	-	5	μA	
$\Delta V_F / \Delta T_A$	Temperature coefficient of forward voltage	I _F =16mA	-	-1.8	-	mV/℃	

Detector Characteristics

Symbol	Parameter	rs	Test Conditions	Min	Тур	Max	Units	Notes
La.	Logic High Output	6N139		-	0.008	80	μA	
Іон	Current	6N138	- I _F =0mA, V _O =V _{CC} =18V,	-	-	200		
ICCL	Logic Low Supply Current		I⊧=1.6mA, V₀=Open, V _{CC} =18V	-	0.5	1.4	mA	
I _{ССН}	Logic High Supply Current		I⊧=0mA, V₀=Open, V _{CC} =18V	-	0.04	8	μΑ	

Transfer Characteristics

Symbol	Paramete	ers	Test Conditions	Min	Тур	Max	Units	Notes
	Current Transfer Ratio	6N139	I _F =0.5mA, V _O =0.4V,	400	2500	-	%	
CTR		6N138	- I⊧=1.6mA, V₀=0.5V,	300	2000	-		
		6N139		500	2000	-		
	Logic Low Output Voltage	out 6N139	I⊧= 0.5mA, I₀= 2mA	-	0.04	0.4	-	
			I _F = 1.6mA, I _O = 8mA	-	0.08	0.4		
V _{OL}			I⊧= 5mA, I₀= 15mA	-	0.11	0.4	V	
			I _F = 12mA, I _O = 24mA	-	0.16	0.4		
		6N138	IF= 1.6mA, Io= 4.8mA	-	0.05	0.4		



Electrical Characteristics $T_A = 0 - 70 \,$ °C, $V_{CC} = 5V$ (unless otherwise specified).

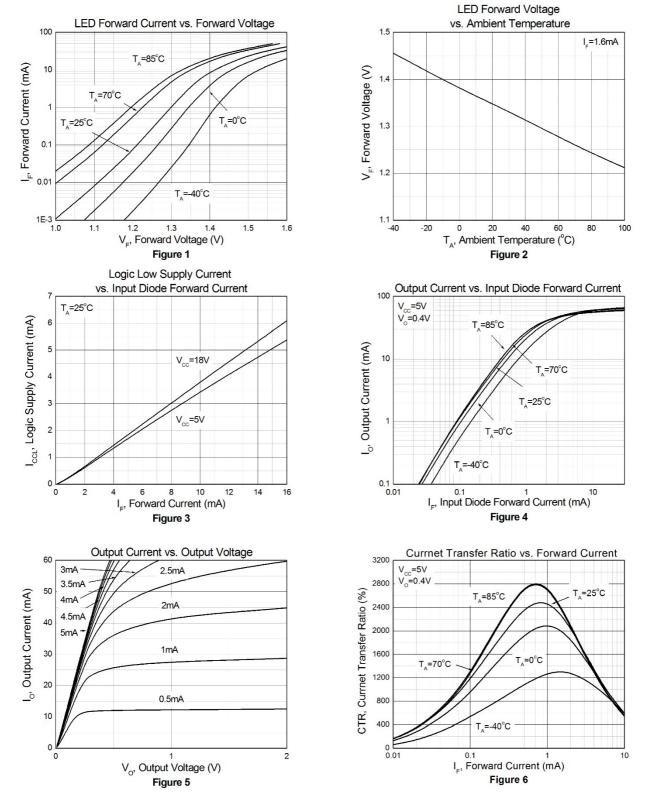
Switching Characteristics

Symbol	Paramete	ers	Test Cond	itions	Min	Тур	Max	Units	Notes
		6N139	I _F = 0.5mA,		-	-	30	- μs	
			R _L = 4.7k	T _A = 25 ⁰ C	-	4.8	25		
-	High to Low		I _F = 12mA,		-	-	2		
T _{PHL}	Propagation Delay		RL= 250	T _A = 25 ⁰ C	-	0.2	1		
		6N138	l _F = 1.6mA,		-	-	15		
			R _L = 2.2k	T _A = 25 ⁰ C	-	1.35	10		
		CN120	l⊧= 0.5mA,		-	-	90	μs	
			R _L = 4.7k	T _A = 25 ⁰ C	-	15	60		
-	Low to High	6N139	I _F = 12mA,		-	-	10		
T _{PLH}	Propagation Delay		RL= 250	T _A = 25 ⁰ C	-	1.6	7		
		6N138	I _F = 1.6mA,		-	-	50		
		01130	R _L = 2.2k	T _A = 25 ⁰ C	-	7.6	35		
<u>CM</u> .	Common Mode Transient		$I_F = 0mA$, $ VCM = 10V_{P-P}$,		1 000				
СМн	Immunity at Logic High		$T_A = 25 ^{\circ}C, R_L = 2.2$	2kΩ	1,000	-	-	V/µs	
CM.	Common Mode Transient		$I_F = 1.6mA$, $ VCM $	$ = 10V_{P-P},$ 1.000		1,000 -		v/μs	
CM∟	Immunity at Logic Low		$T_A = 25 ^{\circ}C, R_L = 2.2$	2kΩ	1,000	-	-		



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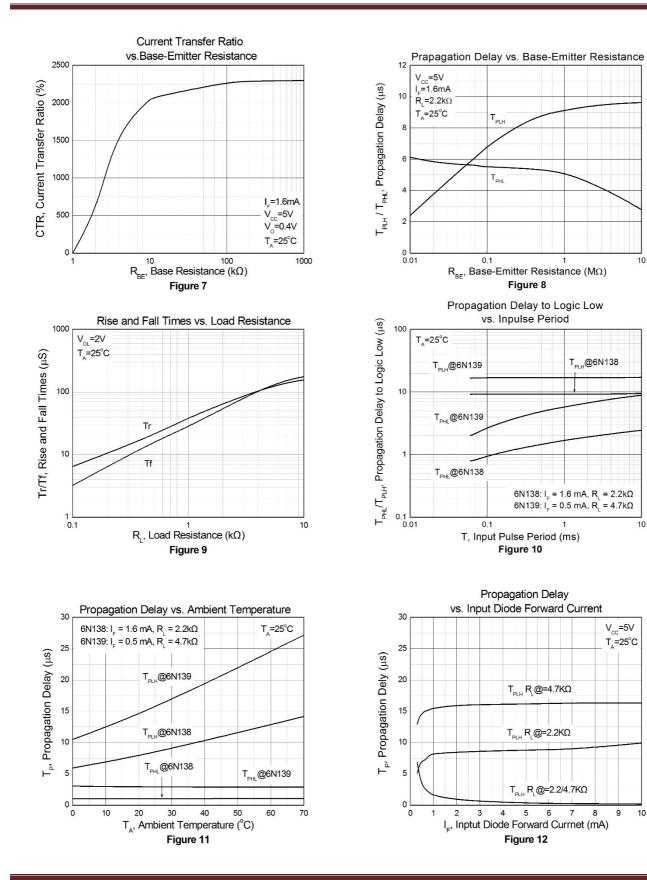
Typical Characteristic Curves





6N138, 6N139

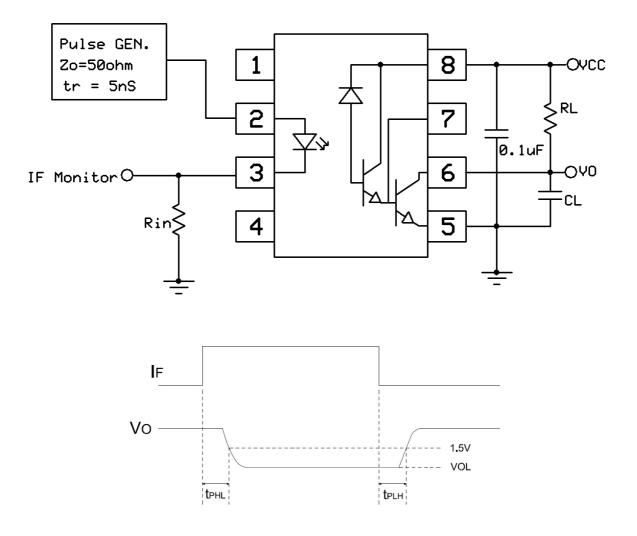
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Test Circuits

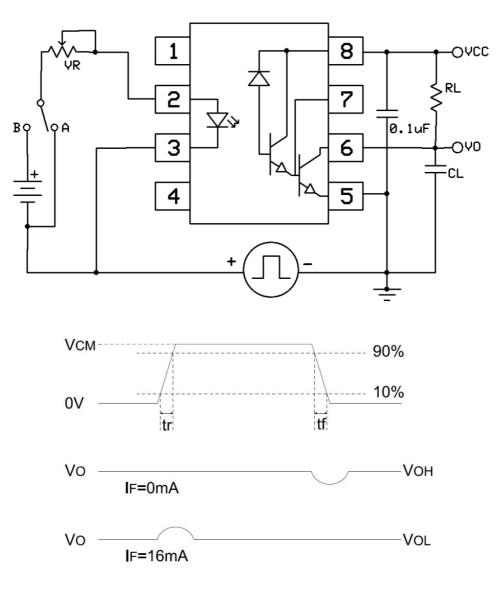


Switching Time Test Circuit



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Test Circuits

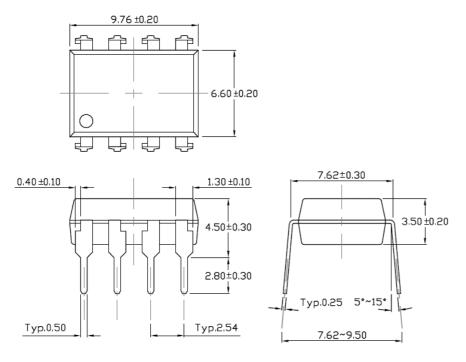


CMR Test Circuit

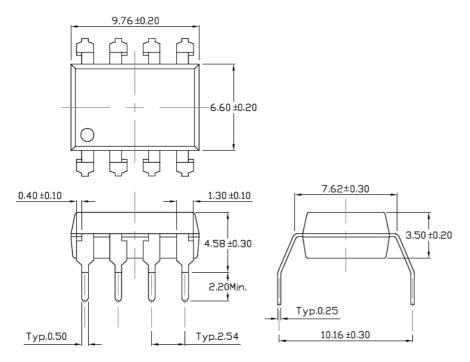


Package Dimension Dimensions in mm unless otherwise stated

Standard DIP – Through Hole

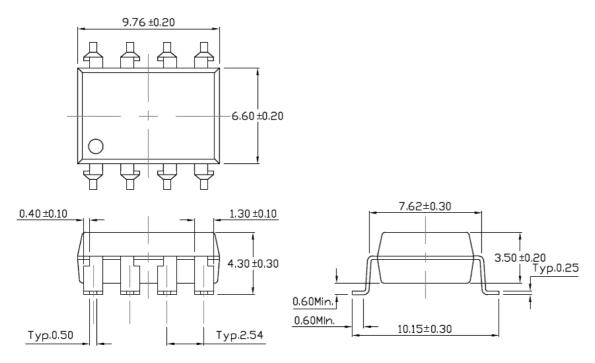


Gullwing (400mil) Lead Forming – Through Hole (M Type)

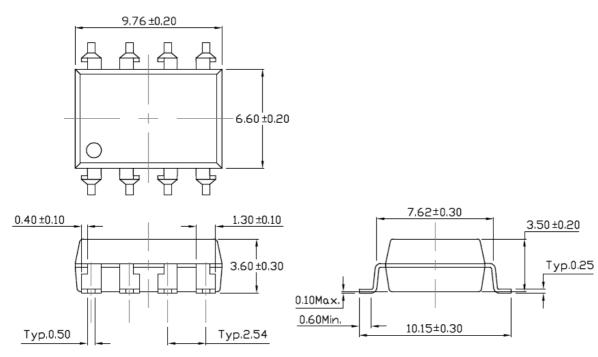




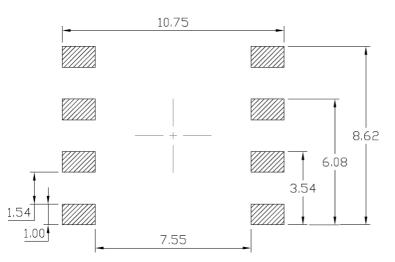
Surface Mount Lead Forming (S Type)



Surface Mount (Low Profile) Lead Forming (SL Type)

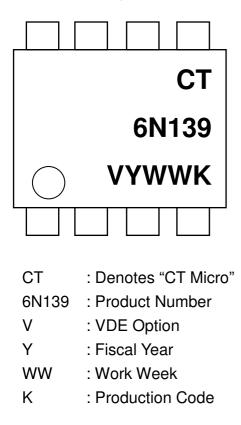






Recommended Solder Mask Dimensions in mm unless otherwise stated

Device Marking





Ordering Information

6N13X(V)(Y)(Z)

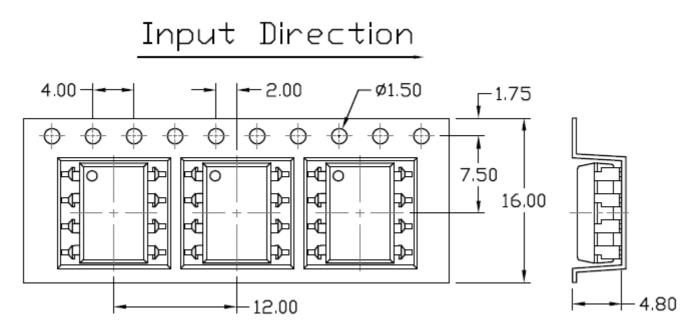
- X = Part No. (8 or 9)
- V = VDE Option (V or None)
- Y = Lead form option (S, SL, M or none)
- Z = Tape and reel option (T1, T2 or none)

Option	Description	Quantity
None	None Standard 8 Pin Dip	
М	Gullwing (400mil) Lead Forming	40 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming- With Option 1 Taping	1000 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming- With Option 2 Taping	1000 Units/Reel

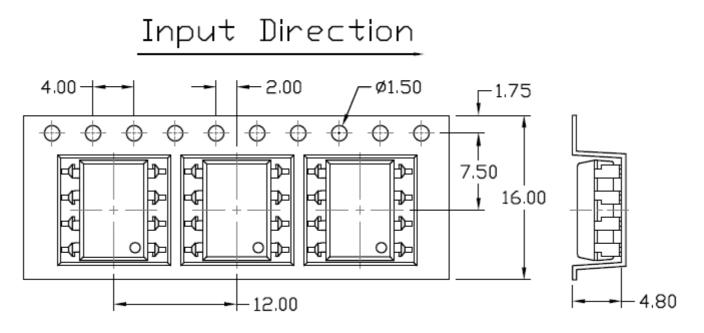


Carrier Tape Specifications Dimensions in mm unless otherwise stated

Option S(T1) & SL(T1)

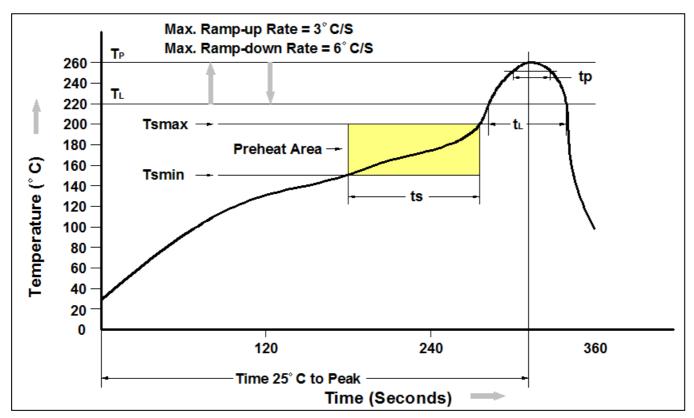


Option S(T2) & SL(T2)





Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200 <i>°</i> C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (TL)	217℃
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260 ℃ +0 ℃ / -5 ℃
Time (t₂) within 5℃ of 260℃	30 seconds
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max
Time 25℃ to Peak Temperature	8 minutes max.



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